















**ESD** 

TVS

MOS

LDO

Diode

Sensor

DC-DC

# **Product Specification**

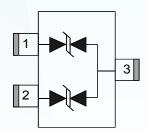
Domestic Part Number	NUP2105L
Overseas Part Number	NUP2105L
▶ Equivalent Part Number	NUP2105L





#### **Dual Line CAN Bus Protector**

The NUP2105L has been designed to protect the CAN transceiver in high-speed and fault tolerant networks from ESD and other harmful transient voltage events. This device provides bidirectional protection for each data line with a single compact SOT-23 package, giving the system designer a low cost option for improving system reliability and meeting stringent EMI requirements.



#### **Features**

- 350 W Peak Power Dissipation per Line (8 x 20sec Waveform)
- Low Reverse Leakage Current (< 100 nA)</p>
- Low Capacitance High-Speed CAN Data Rates
- IEC Compatibility: IEC 61000-4-2 (ESD): Level 4
  - IEC 61000-4-4 (EFT): 40 A 5/50ns
  - IEC 61000-4-5 (Lighting) 8.0 A (8/20μs)
- ISO 7637<sup>-1</sup>, Nonrepetitive EMI Surge Pulse 2, 9.5 A (1 x 50µs)
- ISO 7637-3, Repetitive Electrical Fast Transient (EFT) EMI Surge Pulses, 50 A (5 x 50 ns)
- Flammability Rating UL 94 V<sup>-</sup>0

### **Applications**

- Industrial Control Networks Smart Distribution Systems (SDS<sup>®</sup>) DeviceNet
- NetworksLow and High-Speed CANFault Tolerant CAN

### **MAXIMUM RATINGS** ( $T_J = 25^{\circ}C$ , unless otherwise specified)

Symbol	Rating	Value	Unit
PPK	Peak Power Dissipation 8 x 20 μs Double Exponential Waveform (Note 1)	350	W
TJ	Operating Junction Temperature Range	55 to 150	°C
TJ	Storage Temperature Range	55 to 150	°C
TL	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body model (HBM)  Machine Model (MM)  IEC 61000 - 4-2 Specification (Contact)	16 400 30	kV V kV

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

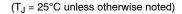


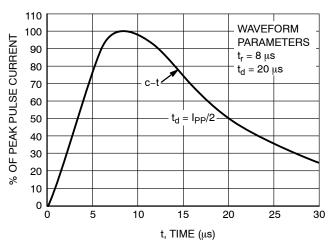
#### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = 25°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>RWM</sub>	Reverse Working Voltage	(Note 2)	24	_	-	V
V <sub>BR</sub>	Breakdown Voltage	I <sub>T</sub> = 1 mA (Note 3)	26.2	-	32	V
I <sub>R</sub>	Reverse Leakage Current	V <sub>RWM</sub> = 24 V	_	15	100	nA
V <sub>C</sub>	Clamping Voltage	I <sub>PP</sub> = 5 A (8 x 20μs Waveform) (Note 4)	-	-	40	V
V <sub>C</sub>	Clamping Voltage	I <sub>PP</sub> = 8 A (8 x 20μ s Waveform) (Note 4)	-	-	44	V
IPP	Maximum Peak Pulse Current	8 x 20µs Waveform (Note 4)	_	_	8.0	Α
CJ	Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz (Line to GND)	-	-	30	pF

<sup>1.</sup> Non-repetitive current pulse per Figure 1.

#### **TYPICAL PERFORMANCE CURVES**







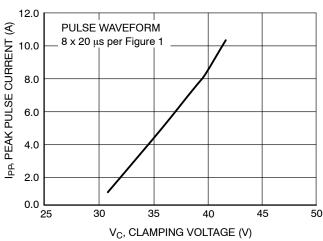


Figure 2. Clamping Voltage vs Peak Pulse Current

<sup>2.</sup> TVS devices are normally selected according to the working peak reverse voltage (V<sub>RWM</sub>), which should be equal or greater than the DC or continuous peak operating voltage level.

<sup>3.</sup>  $V_{BR}$  is measured at pulse test current  $I_{T}$ .

<sup>4.</sup> Pulse waveform per Figure 1.



#### **TYPICAL PERFORMANCE CURVES**

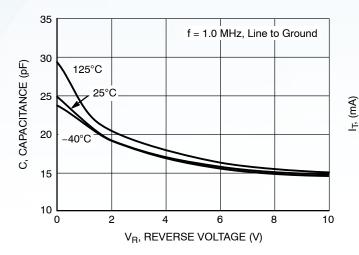


Figure 3. Typical Junction Capacitance vs Reverse Voltage

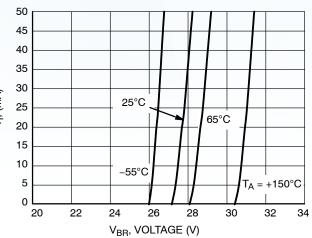


Figure 4. V<sub>BR</sub> versus I<sub>T</sub> Characteristics

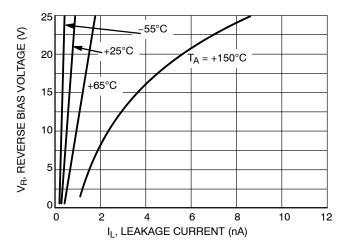


Figure 5. I<sub>R</sub> versus Temperature Characteristics

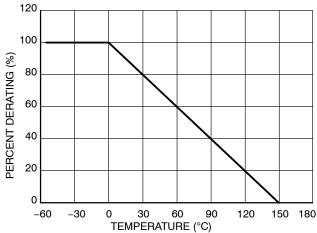
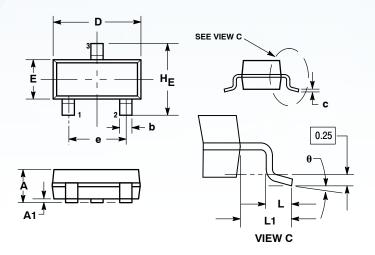


Figure 6. Temperature Power Dissipation Derating



### **Outline Drawing - SOT-23**



	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°		10°

STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE

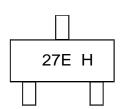
- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
  THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM
  THICKNESS OF BASE MATERIAL.

### Marking



## **Ordering information**

Order code	Package	Baseqty	Deliverymode
NUP2105L	SOT-23	3000	Tape and reel



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